

PATENT ASSIGNMENT

Electronic Version v1.1

Stylesheet Version v1.1

SUBMISSION TYPE:	CORRECTIVE ASSIGNMENT										
NATURE OF CONVEYANCE:	Corrective Assignment to correct the ASSIGNEE "Freescale Semiconductor, Inc." previously recorded on Reel 024203 Frame 0347. Assignor(s) hereby confirms the Assignor(s) hereby confirm that the ASSIGNEES are Freescale Semiconductor, Inc. and ST Microelectronics (Crolles 2) SAS..										
CONVEYING PARTY DATA											
<table border="1"><thead><tr><th>Name</th><th>Execution Date</th></tr></thead><tbody><tr><td>ANISSA LAGHA</td><td>11/26/2007</td></tr><tr><td>ROBERT FOX</td><td>10/29/2007</td></tr><tr><td>LUCILLE BROUSSOUS</td><td>04/01/2010</td></tr><tr><td>DIDIER LEVY</td><td>04/02/2010</td></tr></tbody></table>		Name	Execution Date	ANISSA LAGHA	11/26/2007	ROBERT FOX	10/29/2007	LUCILLE BROUSSOUS	04/01/2010	DIDIER LEVY	04/02/2010
Name	Execution Date										
ANISSA LAGHA	11/26/2007										
ROBERT FOX	10/29/2007										
LUCILLE BROUSSOUS	04/01/2010										
DIDIER LEVY	04/02/2010										
RECEIVING PARTY DATA											
<table border="1"><tr><td>Name:</td><td>Freescale Semiconductor, Inc.</td></tr><tr><td>Street Address:</td><td>6501 William Cannon Dr.</td></tr><tr><td>City:</td><td>Austin</td></tr><tr><td>State/Country:</td><td>TEXAS</td></tr><tr><td>Postal Code:</td><td>78735</td></tr></table>		Name:	Freescale Semiconductor, Inc.	Street Address:	6501 William Cannon Dr.	City:	Austin	State/Country:	TEXAS	Postal Code:	78735
Name:	Freescale Semiconductor, Inc.										
Street Address:	6501 William Cannon Dr.										
City:	Austin										
State/Country:	TEXAS										
Postal Code:	78735										
<table border="1"><tr><td>Name:</td><td>ST MICROELECTRONICS (CROLLES2) SAS</td></tr><tr><td>Street Address:</td><td>850 RUE JEAN MONNET</td></tr><tr><td>City:</td><td>CROLLES</td></tr><tr><td>State/Country:</td><td>FRANCE</td></tr></table>		Name:	ST MICROELECTRONICS (CROLLES2) SAS	Street Address:	850 RUE JEAN MONNET	City:	CROLLES	State/Country:	FRANCE		
Name:	ST MICROELECTRONICS (CROLLES2) SAS										
Street Address:	850 RUE JEAN MONNET										
City:	CROLLES										
State/Country:	FRANCE										
PROPERTY NUMBERS Total: 1											
<table border="1"><thead><tr><th>Property Type</th><th>Number</th></tr></thead><tbody><tr><td>Application Number:</td><td>12681119</td></tr></tbody></table>		Property Type	Number	Application Number:	12681119						
Property Type	Number										
Application Number:	12681119										
CORRESPONDENCE DATA											
Fax Number: (512)996-6853											
<i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i>											
Phone: 512-996-6839											
Email: Tracy.Buffett@freescale.com											
Correspondent Name: Freescale Semiconductor, Inc.											

CH \$40.00 12681119

501307270

PATENT
REEL: 025072 FRAME: 0735

Address Line 1: 7700 W. Parmer Lane
Address Line 2: TX32/PL02
Address Line 4: Austin, TEXAS 78729

ATTORNEY DOCKET NUMBER: MT10731CF

NAME OF SUBMITTER: Tracy Buffett

Total Attachments: 17

source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page1.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page2.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page3.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page4.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page5.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page6.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page7.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page8.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page9.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page10.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page11.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page12.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page13.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page14.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page15.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page16.tif
source=MT10731CF-20100408-USPTO-EPAS-with-assignment-as-filed#page17.tif



United States Patent and Trademark Office

[Home](#) | [Site Index](#) | [Search](#) | [Guides](#) | [Contacts](#) | [eBusiness](#) | [eBiz alerts](#) | [News](#) | [Help](#)*Electronic Patent Assignment System***Confirmation Receipt**

Your assignment has been received by the USPTO.
The coversheet of the assignment is displayed below:

PATENT ASSIGNMENT

Electronic Version v1.1

Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT										
NATURE OF CONVEYANCE:	ASSIGNMENT										
CONVEYING PARTY DATA											
<table border="1"><thead><tr><th>Name</th><th>Execution Date</th></tr></thead><tbody><tr><td>ANISSA LAGHA</td><td>11/26/2007</td></tr><tr><td>ROBERT FOX</td><td>10/29/2007</td></tr><tr><td>LUCILLE BROUSSOUS</td><td>04/01/2010</td></tr><tr><td>DIDIER LEVY</td><td>04/02/2010</td></tr></tbody></table>	Name	Execution Date	ANISSA LAGHA	11/26/2007	ROBERT FOX	10/29/2007	LUCILLE BROUSSOUS	04/01/2010	DIDIER LEVY	04/02/2010	
Name	Execution Date										
ANISSA LAGHA	11/26/2007										
ROBERT FOX	10/29/2007										
LUCILLE BROUSSOUS	04/01/2010										
DIDIER LEVY	04/02/2010										
RECEIVING PARTY DATA											
<table border="1"><tr><td>Name:</td><td>FREESCALE SEMICONDUCTOR INC.</td></tr><tr><td>Street Address:</td><td>6501 WILLIAM CANNON DRIVE WEST</td></tr><tr><td>City:</td><td>AUSTIN</td></tr><tr><td>State/Country:</td><td>TEXAS</td></tr><tr><td>Postal Code:</td><td>78735</td></tr></table>	Name:	FREESCALE SEMICONDUCTOR INC.	Street Address:	6501 WILLIAM CANNON DRIVE WEST	City:	AUSTIN	State/Country:	TEXAS	Postal Code:	78735	
Name:	FREESCALE SEMICONDUCTOR INC.										
Street Address:	6501 WILLIAM CANNON DRIVE WEST										
City:	AUSTIN										
State/Country:	TEXAS										
Postal Code:	78735										
PROPERTY NUMBERS Total: 1											
<table border="1"><thead><tr><th>Property Type</th><th>Number</th></tr></thead><tbody><tr><td>Application Number:</td><td>12681119</td></tr></tbody></table>	Property Type	Number	Application Number:	12681119							
Property Type	Number										
Application Number:	12681119										

CORRESPONDENCE DATA

Fax Number: (512)996-6854
Correspondence will be sent via US Mail when the fax attempt is unsuccessful.
Phone: 5129966839
Email: USADOCKETING@FREESCALE.COM
Correspondent Name: FREESCALE SEMICONDUCTOR, INC. LAW DEPART
Address Line 1: 7700 WEST PARMER LANE MD:TX32/PL02
Address Line 4: AUSTIN, TEXAS 78729

ATTORNEY DOCKET NUMBER:	MT10731CF
--------------------------------	-----------

NAME OF SUBMITTER:	Rosemary Hoffert
---------------------------	------------------

Signature:	/Rosemary Hoffert/
-------------------	--------------------

Date:	04/08/2010
--------------	------------

Total Attachments: 15

source=MT10731CF-USA-Assignment#page1.tif
source=MT10731CF-USA-Assignment#page2.tif
source=MT10731CF-USA-Assignment#page3.tif
source=MT10731CF-USA-Assignment#page4.tif
source=MT10731CF-USA-Assignment#page5.tif
source=MT10731CF-USA-Assignment#page6.tif
source=MT10731CF-USA-Assignment#page7.tif
source=MT10731CF-USA-Assignment#page8.tif
source=MT10731CF-USA-Assignment#page9.tif
source=MT10731CF-USA-Assignment#page10.tif
source=MT10731CF-USA-Assignment#page11.tif
source=MT10731CF-USA-Assignment#page12.tif
source=MT10731CF-USA-Assignment#page13.tif
source=MT10731CF-USA-Assignment#page14.tif
source=MT10731CF-USA-Assignment#page15.tif

RECEIPT INFORMATION

EPAS ID: PAT1164412
Receipt Date: 04/08/2010
Fee Amount: \$40

[Return to home page](#)

[| HOME |](#) [INDEX |](#) [SEARCH |](#) [eBUSINESS |](#) [CONTACT US |](#) [PRIVACY STATEMENT](#)

ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **LAGHA ANISSA, MONTBONNOT FRANCE, FOX ROBERT, SINGAPORE, SINGAPORE, BROUSSOUS LUCILE, GONCELIN, FRANCE and LEVY DIDIER, SAINT NAZAIRE LES EYMES, FRANCE** have sold, assigned and transferred, and do hereby sell, assign and transfer, unto FREESCALE SEMICONDUCTOR, INC., a corporation of the State of Delaware, having its principal office in Austin, Texas, United States of America, and unto ST MICROELECTRONICS (CROLLES 2) SAS., a corporation of France, having its principal office 850 rue Jean Monnet in Crolles, France and their successors, assigns, and legal representatives, the entire right, title and interest for the United States of America and France in and to certain inventions relating to improvements in **METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE AND SEMICONDUCTOR DEVICE OBTAINABLE WITH SUCH A METHOD** (Docket No. MT10731CF USA), described, illustrated and claimed in an application for Letters Patent of the United States of America and France executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

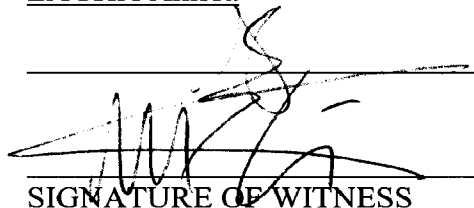
We hereby also sell, assign and transfer unto FREESCALE SEMICONDUCTOR, INC. and unto ST MICROELECTRONICS (CROLLES 2) SAS, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America and France, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize FREESCALE SEMICONDUCTOR, INC. and ST MICROELECTRONICS (CROLLES 2) SAS to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America and France under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America and the Commissioner of Patents of France to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to FREESCALE SEMICONDUCTOR, INC. and to ST MICROELECTRONICS (CROLLES 2) SAS, for the sole use and benefit of FREESCALE SEMICONDUCTOR, INC., and ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to FREESCALE SEMICONDUCTOR, INC. and ST MICROELECTRONICS (CROLLES 2) SAS

We agree that, when requested, we will, without charge to FREESCALE SEMICONDUCTOR, INC. or to ST MICROELECTRONICS (CROLLES 2) SAS. but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in FREESCALE SEMICONDUCTOR, INC. and in ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives or nominees.

We covenant with FREESCALE SEMICONDUCTOR, INC. and ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.


LAGHA Anissa


SIGNATURE OF WITNESS

DATE: 11/26/07

DATE: 11/26/07
(Month-Day-Year)

MATHEO CLAIN
PRINTED NAME OF WITNESS


SIGNATURE OF WITNESS

DATE: 11/26/07
(Month-Day-Year)

COLLAUITE CHABANNE
PRINTED NAME OF WITNESS

FOX Robert

DATE: _____

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

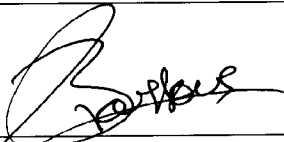
SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

BROUSSOUS Lucille

DATE: _____



SIGNATURE OF WITNESS

DATE: November 26th 2007
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

LEVY Didier

DATE: _____

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **LAGHA ANISSA, MONTBONNOT FRANCE, FOX ROBERT, SINGAPORE, SINGAPORE, BROUSSOUS LUCILE, GONCELIN, FRANCE and LEVY DIDIER, SAINT NAZAIRE LES EYMES, FRANCE** have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, Texas, United States of America, and unto **ST MICROELECTRONICS (CROLLES 2) SAS.**, a corporation of France, having its principal office 850 rue Jean Monnet in Crolles, France and their successors, assigns, and legal representatives, the entire right, title and interest for the United States of America and France in and to certain inventions relating to improvements in **METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE AND SEMICONDUCTOR DEVICE OBTAINABLE WITH SUCH A METHOD** (Docket No. MT10731CF USA), described, illustrated and claimed in an application for Letters Patent of the United States of America and France executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.** and unto **ST MICROELECTRONICS (CROLLES 2) SAS**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America and France, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** and **ST MICROELECTRONICS (CROLLES 2) SAS** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America and France under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America and the Commissioner of Patents of France to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.** and to **ST MICROELECTRONICS (CROLLES 2) SAS**, for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.**, and **ST MICROELECTRONICS (CROLLES 2) SAS**. their successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to **FREESCALE SEMICONDUCTOR, INC.** and **ST MICROELECTRONICS (CROLLES 2) SAS**

We agree that, when requested, we will, without charge to FREESCALE SEMICONDUCTOR, INC. or to ST MICROELECTRONICS (CROLLES 2) SAS. but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in FREESCALE SEMICONDUCTOR, INC. and in ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives or nominees.

We covenant with FREESCALE SEMICONDUCTOR, INC. and ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.

LAGHA Anissa

DATE: _____

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

FOX Robert

Robert J. Fox III

DATE: 10-29-2007

Michelle Sureddin
SIGNATURE OF WITNESS

DATE: 10-29-2007
(Month-Day-Year)

Michelle Sureddin
PRINTED NAME OF WITNESS

[Signature]
SIGNATURE OF WITNESS

DATE: 10-29-2007
(Month-Day-Year)

Dejan Jovanovic
PRINTED NAME OF WITNESS

BROUSSOUS Lucille

DATE: _____

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

LEVY Didier

DATE: _____

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **LAGHA ANISSA, MONTBONNOT FRANCE, FOX ROBERT, SINGAPORE, SINGAPORE, BROUSSOUS LUCILE, GONCELIN, FRANCE and LEVY DIDIER, SAINT NAZAIRE LES EYMES, FRANCE** have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, Texas, United States of America, and unto **ST MICROELECTRONICS (CROLLES 2) SAS.**, a corporation of France, having its principal office 850 rue Jean Monnet in Crolles, France and their successors, assigns, and legal representatives, the entire right, title and interest for the United States of America and France in and to certain inventions relating to improvements in **METHOD FOR MANUFACTURING A SEMICONDUCTOR DEVICE AND SEMICONDUCTOR DEVICE OBTAINABLE WITH SUCH A METHOD** (Docket No. MT10731CF USA), described, illustrated and claimed in an application for Letters Patent of the United States of America and France executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.** and unto **ST MICROELECTRONICS (CROLLES 2) SAS**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America and France, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** and **ST MICROELECTRONICS (CROLLES 2) SAS** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America and France under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America and the Commissioner of Patents of France to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.** and to **ST MICROELECTRONICS (CROLLES 2) SAS**, for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.**, and **ST MICROELECTRONICS (CROLLES 2) SAS**. their successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to **FREESCALE SEMICONDUCTOR, INC.** and **ST MICROELECTRONICS (CROLLES 2) SAS**

We agree that, when requested, we will, without charge to FREESCALE SEMICONDUCTOR, INC. or to ST MICROELECTRONICS (CROLLES 2) SAS. but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in FREESCALE SEMICONDUCTOR, INC. and in ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives or nominees.

We covenant with FREESCALE SEMICONDUCTOR, INC. and ST MICROELECTRONICS (CROLLES 2) SAS. their successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.

LAGHA Anissa

DATE: _____

SIGNATURE OF WITNESS
DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS
DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

FOX Robert

DATE: _____

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

BROUSSOUS Lucille



DATE: 01 April 2010


SIGNATURE OF WITNESS

DATE: 01 April 2010
(Month-Day-Year)

ANTOINE MALLET
PRINTED NAME OF WITNESS


SIGNATURE OF WITNESS

DATE: April - 01 - 2010
(Month-Day-Year)

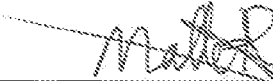
VECHICHIAN Ardem
PRINTED NAME OF WITNESS

LEVY Didier



DATE:

2/4/2010



SIGNATURE OF WITNESS

DATE:

02 April 2010
(Month-Day-Year)

ANTOINE MALLET
PRINTED NAME OF WITNESS



SIGNATURE OF WITNESS

DATE:

April-01-2010
(Month-Day-Year)

KECHICHIAN A-dam
PRINTED NAME OF WITNESS